



C. Gemme - INFN Genova

ATLAS Italia – 17/5/2012, Milano

Inputs da M.Citterio, S.Coelli, G.Darbo, A.Gabrielli, C.Meroni, P.Morettini

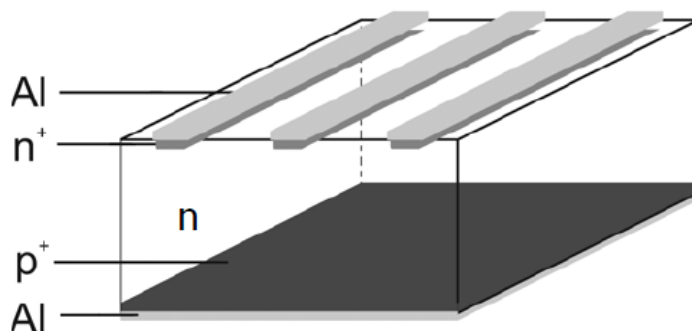
- ✓ IBL: Stato del progetto
 - Moduli: sensori, elettronica, ibridizzazione, module flex
 - Stave, flex, integrazione
 - Servizi: PP2 e ROD
- ✓ Richieste finanziarie

Sensors



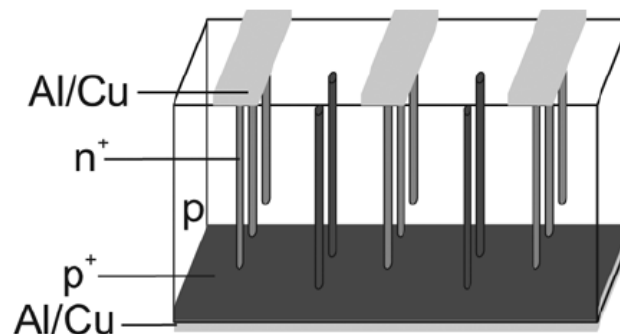
Planar sensor – n-in-n

Charges are collected at the strip surface



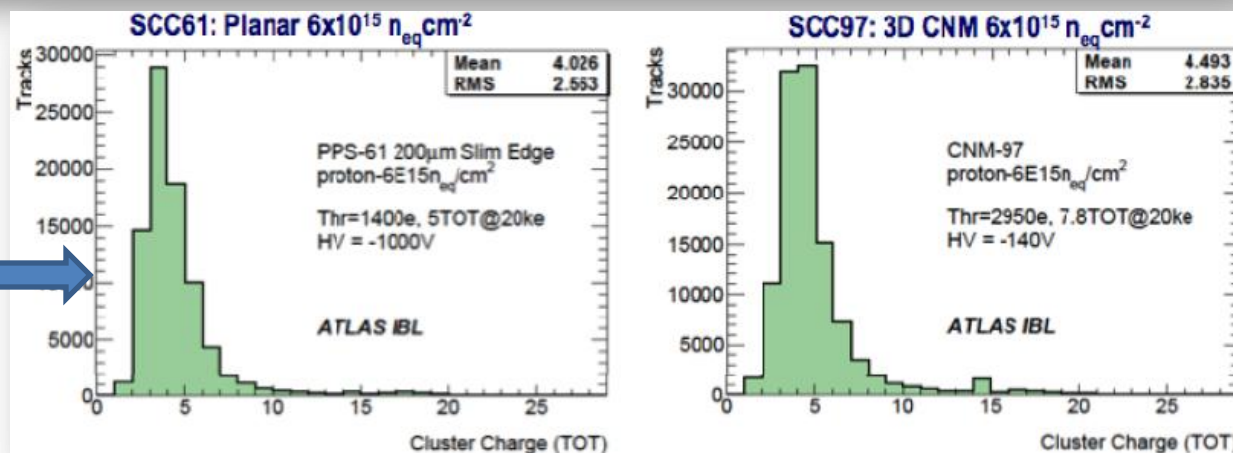
3D sensor

Charges are collected at the bulk implanted electrodes



Test Beam results
show that the sensors
match IBL requirements.

Charge collection:



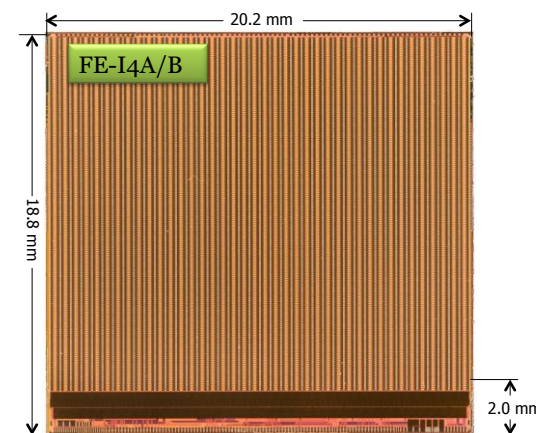
✓ Production Status – assuming 75% planar and 25% 3D

- Planar sensors from CiS: 424 good double chip (DC) tiles (89.1 % yield) - IBL needs 168
- 3D sensors from CNM and FBK: 306 good tiles as today (62% yield) – IBL needs 112

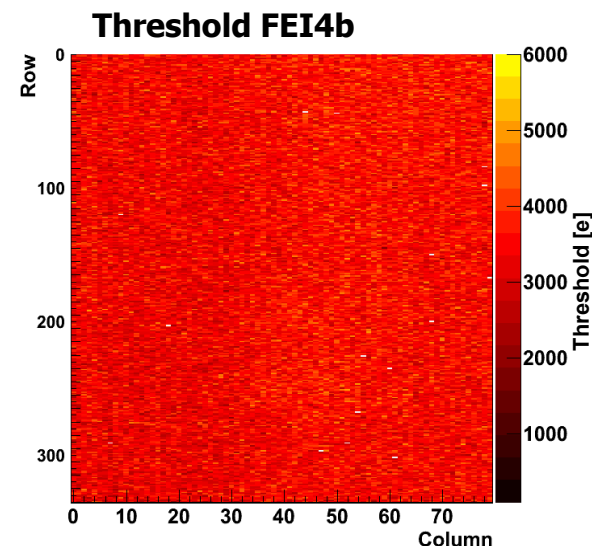
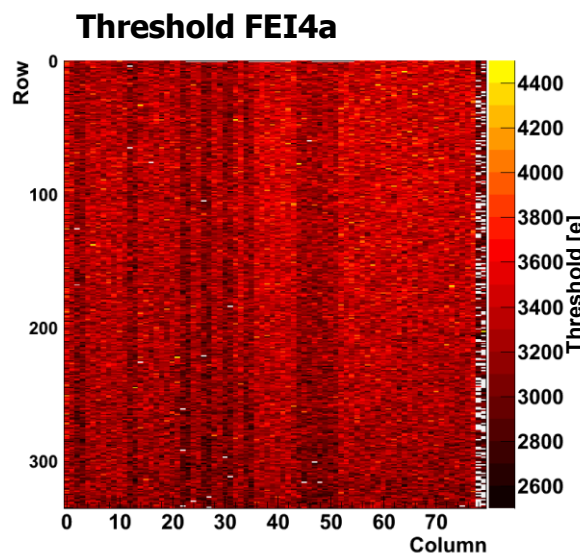
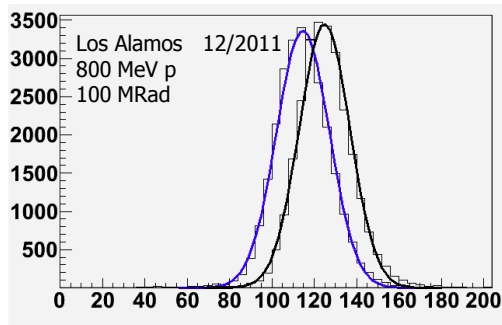
Electronics



- ✓ First version FEI4a for validation and IBL prototypes (32 FE-I4A wafers received in 2010/11)
- ✓ FEI4b features: minor fixes + r/o functionalities + uniform pixel matrix + Power functionality
- ✓ First FEI4b delivery in Dec. 2011
- ✓ FEI4b now in production (30 wafers) and wafer probing is almost completed (yield ~60%)



FEI4b noise before and after irradiation:
114e → 124e (both tuned)

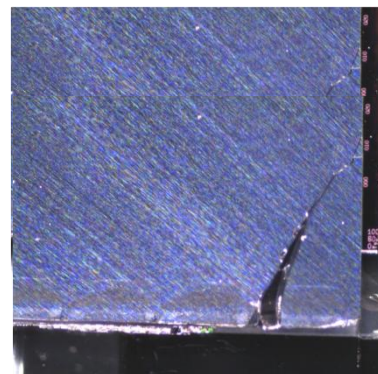


Bump-Bonding – Thin Modules

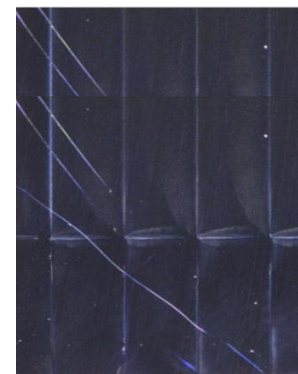


- ✓ 125 modules built at IZM using FEI4a; assembled (glue hybrid and wirebond) and qualified in two assembly sites (Genova/Bonn)
 - ✓ Thin module prototypes (100 and 150 μm thick electronics):
 - Thin module process steps: ① FE-I4 wafers thinned – ② **glued on glass support wafer** – ③ bump deposition – ④ dicing wafer & substrate – ⑤ flip-chip & reflow – ⑥ **substrate wafer removal by power laser**.
 - Some cracks during the process of laser release of the substrate.
 - mainly in 100 μm thin modules
 - Decided to go to **150 μm** thick chips for IBL module production (safety)
- Ge** • Module flex design is being finalized for the final submission (Genova).
- **Module PRR 6-7 June2012**

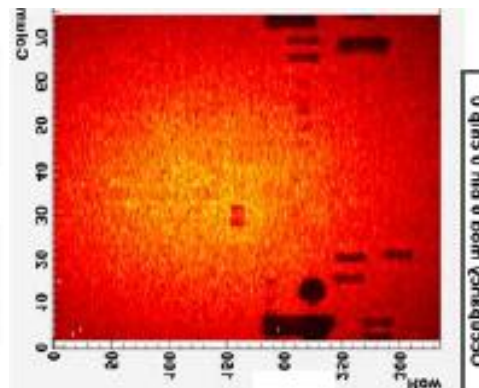
Ge/Mi



Cracks developed in the FE-I4 back side



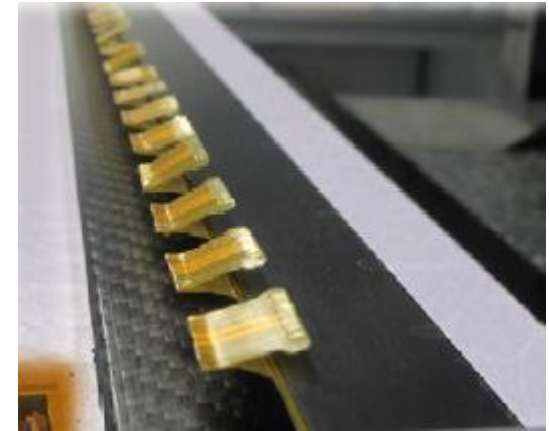
Am source scan
SMDs visible



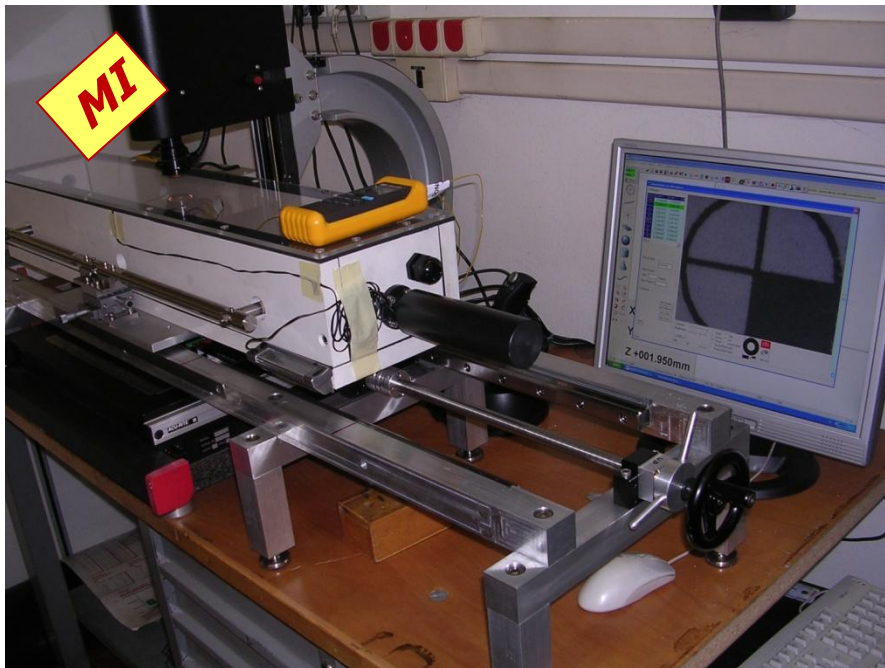
Staves



- ✓ Staves are Made of carbon foam with a K13C omega, a faceplate and a Ti pipe of 1.5 mm ID and 0.1 mm wall thickness for cooling.
- ✓ Stave Production has started and 6 staves have already been delivered for module loading.
 - Planned to produce 33 staves → load 24 (14 needed for IBL).



EXPERIMENTAL MEASUREMENT OF THE STAVE DEFORMATION INDUCED BY THE COOLING



TEST OF INFRARED
TRANSPARENT
MATERIALS FOR
THERMAL IMAGE
TAKEN USING A I.R.
CAMERA (FLIR)

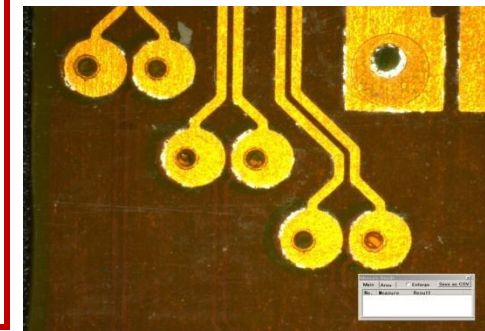
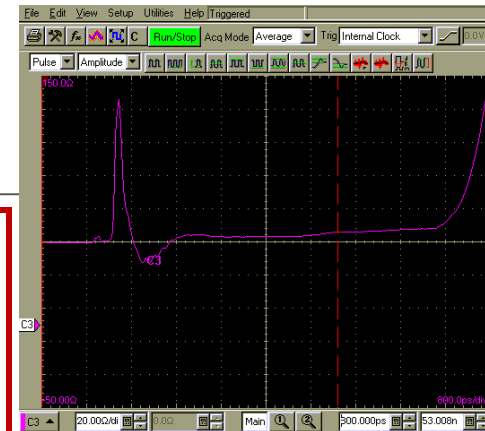
TEST BOX INSTALLED IN THE LASA METROLOGY LAB.
COOLED USING NITROGEN. OPTICAL MEASUREMENT OF
THE STAVE DISPLACEMENT IN SEVERAL POINTS
CONSTRAINS ATTACHED TO INVAR REFERENCE BAR
TEMPERATURE THERMORESISTANCE PT100 SENSORS

Flex

GE

Mix of 4 Cu-layers and 2 Al-layers for the LV lines. Total thickness ~ 450 μm . Special fabrication for the Al-Cu vias.

- ✓ Folded Wings to provide connectivity to the FEs.
- ✓ 6 prototype sets delivered in March. Test in Ge, Slac, Mi.
 - Test in Genova to validate layout. Critical the Al/Cu vias and maintain low resistivity on the LV lines. 20% higher than expected \rightarrow vias to be improved.
 - Full production, minor modifications on the Al-Cu vias, will **restart in few days**.



First prototype of stave with flex is being assembled in these days. Real stave, services, FEI4a modules.

Assembled stave PRR In July.

Layer Name	Type	Material	Thickness (μm)
Coverlay	Dielectric	KAPTON	12.5
		GLUE	12.5
1 TOP (HV)	Conductor	Copper	19
	Dielectric	Pyralux 25 μm	25
LVDS2	Conductor	Copper	18
	Dielectric	GLUE	25
1 GLUE	Dielectric	GLUE	25
2 GND1	Conductor	Copper	5
	Dielectric	Pyralux 75 μm	75
LVDS1	Conductor	Copper	19
	Dielectric	GLUE	25
2 GLUE	Dielectric	Kapton 25 μm	25
	Dielectric	GLUE	25
Aluminium	Plane	Aluminium	50
GLUE			
Al	Dielectric	Kapton 12.5 μm	from 40 to 60
GLUE			
Aluminium	Plane	Aluminium	50
		GLUE	12.5
Coverlay	Dielectric	KAPTON	12.5

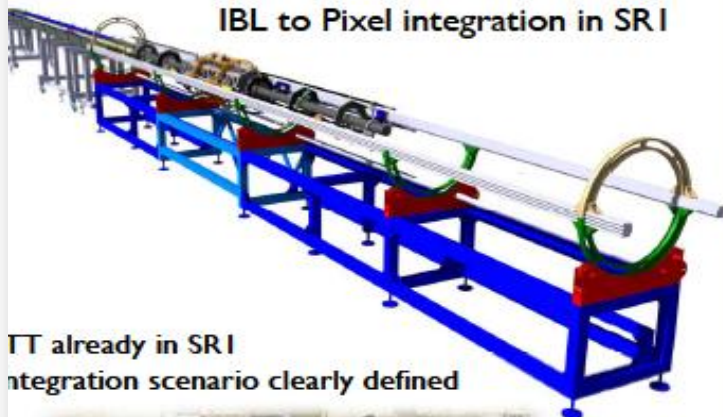
Installation



Two viable options are investigated:

- IBL to Pixel integration in the surface building associated to nSQP installation
- IBL to ATLAS integration in the pit

IBL to Pixel integration in SR I

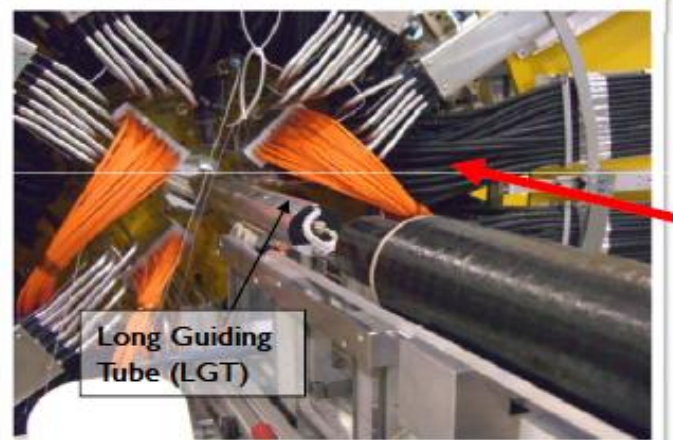
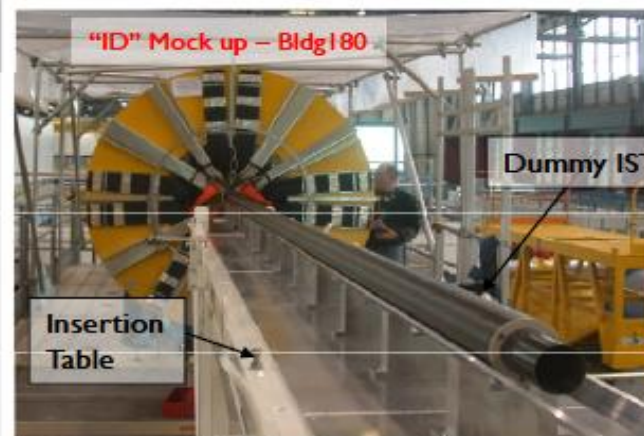


TT already in SR I
Integration scenario clearly defined



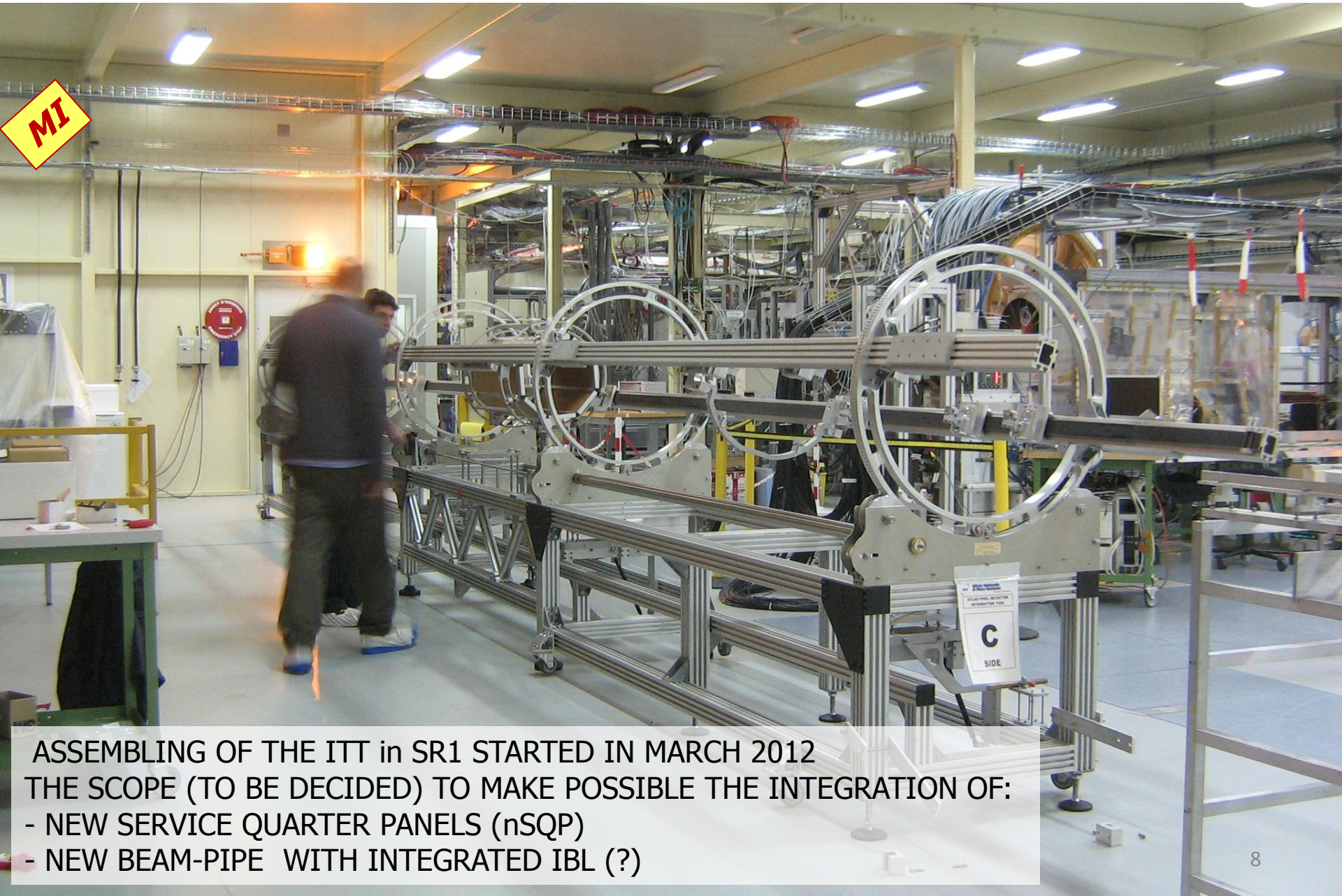
Pixel Integration & Testing Tool

IBL to ATLAS integration in the pit



Decision if to extract the Pixel package to change the services panels (nSQP) will be taken on 12-13 June review!

ATLAS PIXEL DETECTOR INTEGRATION AND TESTING TOOL (ITT) MARCH 2012 SET-UP INTO CERN CLEAN ROOM SR-1



ASSEMBLING OF THE ITT in SR1 STARTED IN MARCH 2012
THE SCOPE (TO BE DECIDED) TO MAKE POSSIBLE THE INTEGRATION OF:

- NEW SERVICE QUARTER PANELS (nSQP)
- NEW BEAM-PIPE WITH INTEGRATED IBL (?)

- ✓ The PP2 crate overall “concept” is kept from the Pixel Detector. The IBL PP2 crate is logically divided in two parts:
 - The voltage regulation (VDD and VVDC)
 - The patch panel for HV (NEW wrt to Pixel) and DCS
- ✓ Most of the electrical boards of which the crate is made are re-designed towards an IBL optimization
 - INPUT Board
 - Output (“BUS”) Board
 - Regulator cards (motherboard and daughterboard)

→ Prototyping Fall 2012, production late 2012/Early 2013
- ✓ The PP2 Control Board (FPGA and ELMB based) stay the same. The ST voltage regulators are used for the IBL regulator boards..
- ✓ In discussion possible splitting of LV power supply to multiplicity 1 instead of 7.

✓ Prototypes:

- ROD minor problems on the first batch are now fixed on the second batch of 5 boards (Bo),
- Current batch of 5 boards have been designed and extensively tested (Bo): till now these tests are OK,
- To allow a parallel ROD firmware development , 3 boards have been temporarily shipped to Wuppertal, Mannheim and Goettingen,
- Setting up a complete data acquisition system: on-detector electronics, optolink , formatting, histo → ready by end of June in SR1 at Cern with boards from Germany.
- Next production foreseen by Summer.

✓ Studying ROD compatibility

With other systems. To be investigated:

- - Diamond Beam Monitor
- - ATLAS Forward Physics
- - Other ATLAS pixel/SCT layers

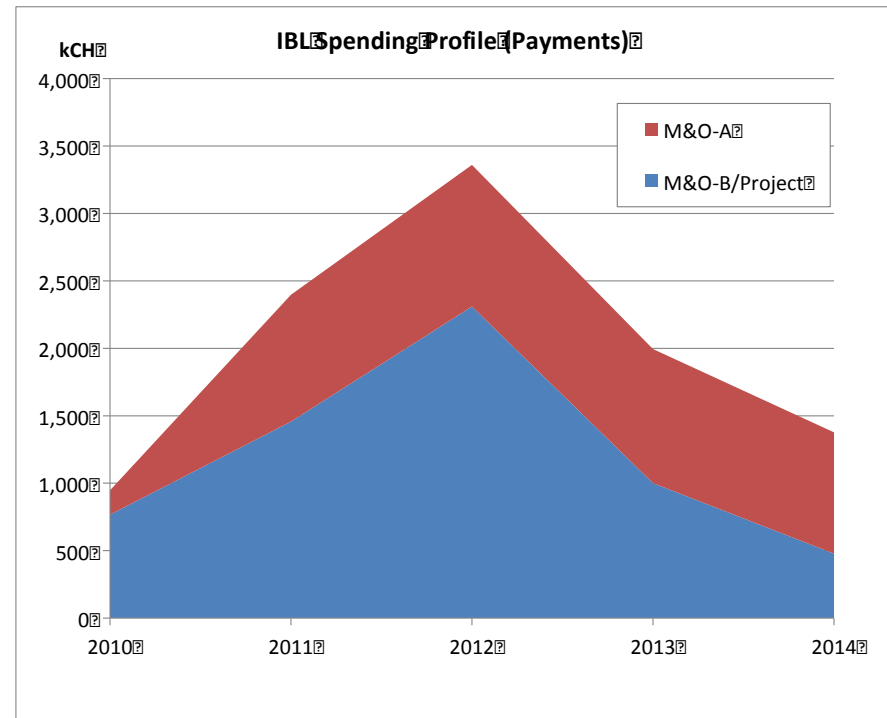


MoU – Spending Profile (annex 5)



✓ Definite MoU

- spending profile considers speed-up IBL schedule
- 2012 value matches CERN-RRB-2012-028 Table 2 (24 April 2012)
- Note: spending profile does not matches



IBL Payment Profile

	2010	2011	2012	2013	2014	Total
M&O-A	180	940	1 050	995	900	4 065
M&O-B/Project	767	1 457	2 310	1 000	478	6 012
Total including DBM	947	2 397	3 360	1 995	1 378	10 077

Finanziamenti 2012-13



- ✓ Mancano le coperture delle pledges (debiti CERN) e il resto dei MOF-A
 - MOF-A mancanti: 126 kCHF (354 totale -228 ass. 2011)
 - Pledges: 230 kCHF (55+15 FEI4B + 60 Bump bonding +100 sensori)
- ✓ Alcuni extra costi:
 - PP2 (ass. 30) e Stave Flex (ass. 40), stima dei costi on-going. Stave (già finanziato). Verifica se possono essere coperti da risparmi su altre voci.
 - Per i referee della CSN1 il progetto (a parte quanto sopra) è (quasi) completamente finanziato.
 - Su ROD, PP2, HV/LV PS ci aspettiamo contributo da istituti DBM (da quantificare).

Anno		sez	cap	finanza				tipologia (MoU)	descrizione
				ric	ric-sj	ass	ass-sj		
2012	Sep-11	BO	con	5		5		A1.6	schede demo e componenti
2012	Sep-11	BO	inv	4		4		A1.6	2 PC linux
2012	Sep-11	BO	app	150		150		A1.6	produzione 20 schede ROD
2012	Sep-11	GE	app	55				A1.2	Produzione FEI4-B (12%) - ANTICPO DAL CERN
2012	Sep-11	GE	app		15			A1.2	Produzione FEI4-B (12%) batch aggiuntivo - ANTICPO DAL CERN
2012	Sep-11	GE	app	95		95		A1.7 (MOF-A)	HV power supply - riconosciuto come MOF-A
2012	Sep-11	GE	app	40		40		A1.8 (MOF-A)	Infrastruttura DAQ per System Test - riconosciuto come MOF-A
2012	Sep-11	GE	app	25		25		A1.5	Produzione moduli
2012	Sep-11	GE	app	40		40		A1.5	Produzione FLEX
2012	Sep-11	MI	con	5		5		A1.6	USB pix per lettura multimoduli
2012	Sep-11	MI	app	30		30		A1.6	crate PP2 e preproduzione 10 schede
2012	Sep-11	MI	app	55		55		A1.7 (MOF-A)	LV Power Supply - riconosciuto come MOF-A
2012	Sep-11	MI	con	30		30		A1.4	extra costi stave production
2012	Sep-11	MI	con	90		30		A1.3	bump bonding - 60 kEu ANTICPO DAL CERN
2012	Sep-11	UD	con	100				A1.1	produzione sensori - ANTICPO DAL CERN
2012	Sep-11	TN	con	4		4		A1.1	probe card
2112		SUM		728	15	513	0		

Richieste ME 2013



✓ Pixel

- Consolidation of the services
- Integration of 4° layer in the software
- Much more work if Pixel is bring on surface. But no direct involvement for the Italian groups.

FTE: ~12 mesi

✓ IBL

- follow up delle delivery dai laboratory, moduli e flex.
- integrazione del detector in Geneva (moduli su stave) e poi Cern (stave attorno alla beam pipe, connessione ai servizi elettrici e raffreddamento)
- electrical, mechanical test in superficie
- stretta collaborazione BO-GE per lo sviluppo SW-HW per l'integrazione nuovi ROD nel sistema di DAQ
- Preparazione nel pozzo all'inserimento + installazione nuovi servizi (PP2)

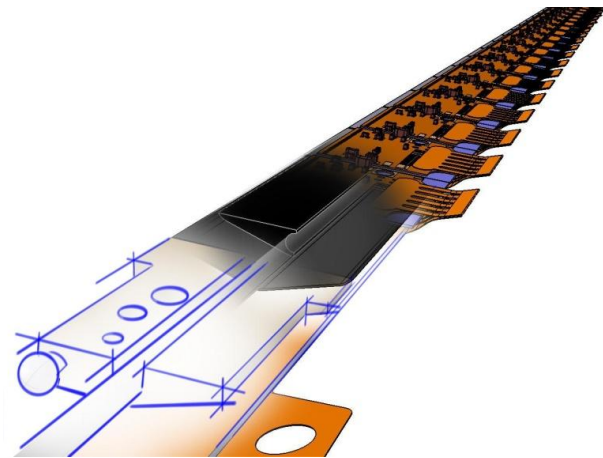
FTE: ~18-24 mesi



- ✓ Addendum to *ATLAS IBL TDR of September 2010* just out:
 - <https://edms.cern.ch/document/1217596/1.6>
 - Covering the accelerated schedule, sensors mixed scenario, the module flex, Stave integration, the beam diamond telescope.
 - [ATLAS Approval and send to LHCC in June](#)
- ✓ First Paper out for comments on CDS: Prototype ATLAS IBL Modules using the FE-I4A Front-End Readout Chip
 - <http://cdsweb.cern.ch/record/1447066>



Insertable B-Layer



Technical Design Report Addendum

Issue:	1
Revision:	6
Reference:	ATLAS TDR 19 Addendum, CERN/ LHCC 2012-xxx
Created:	1 March 2012
Last modified:	11 May 2012
Prepared By:	ATLAS IBL Community

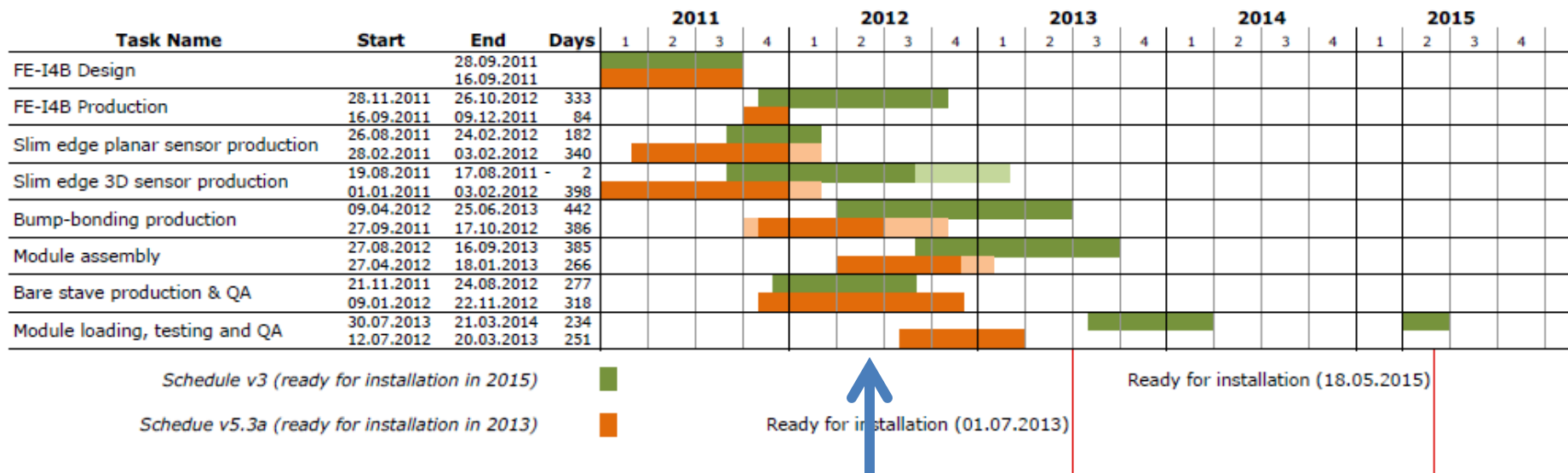
Spares



Schedule



- ✓ New schedule is being updated in these days. Pixel package extraction for services replacement could have an impact on it.

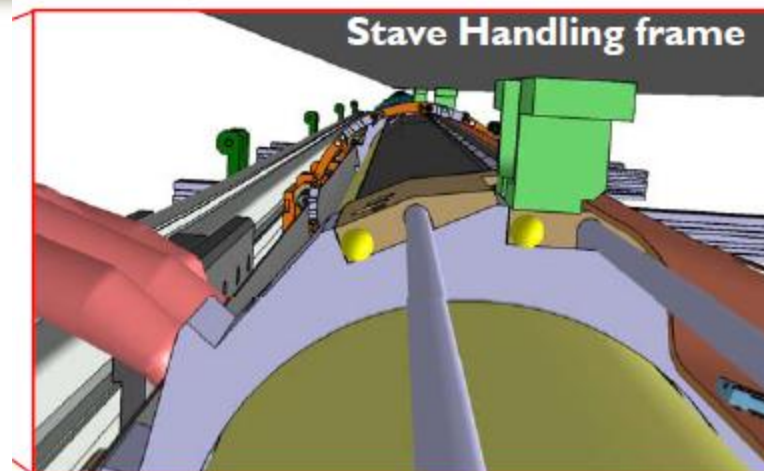
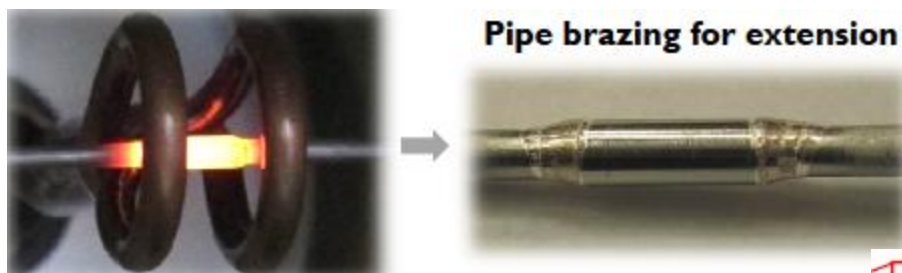


*A parte i sensori,
gli altri item sono ~ tutti in ritardo*

Stave Integration



- ✓ Modules loaded in Geneva, wirebonded to the flex wings and fully qualified.
- ✓ Once staves are ready integration of the cooling pipes is done at Cern and arrangement of the staves around the beampipe is done.



MoU & RRB Tables



✓ Payment table (CERN-RRB-2012-028)

- Recognized 475 kCHF till 2011
- For 2012 expected 407 kCHF (of which 220kCHF from open commitments)

Project (FA)	Contributions: plan 2012				
	2010-11 kCHF	2012-tot kCHF	2010-12 kCHF	MoU ref. kCHF	%
Canada	40	52	92	100	91.5
Czech Republic	27	0	28	27	101.7
France IN2P3	316	140	456	576	79.2
Germany BMBF	467	450	917	1 225	74.9
Germany DESY	-	50	50	72	69.1
Germany MPI	11	-	11	-	
Italy	475	407	882	1 047	84.3
Japan	-	71	71	92	76.9
Netherlands	172	23	195	211	92.5
Norway	12	57	69	73	95.3
Slovenia	65	30	95	88	108.5
Spain	-	108	108	132	81.6
Switzerland	210	260	470	830	56.6
Taipei	-	-	-	41	-
United Kingdom	14	93	106	106	100.0
US DOE & NSF	303	320	622	846	73.6
CERN	111	249	360	546	66.0
Total	2 223	2 310	4 533	6 012	75.4